

Vishay Semiconductors

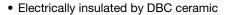
INT-A-PAK Power Modules Ultrafast Diodes, 300 A



INT-A-PAK

PRODUCT SUMMARY				
I _{F(AV)} at T _C	300 A at 48 °C			
V_{R}	600 V			
t _{rr} (typical)	130 ns			
I _{F(DC)} at T _C	230 A at 100 °C			

FEATURES





- Standard JEDEC package
- Simplified mechanical designs, rapid assembly
- High surge capability
- Large creepage distances
- UL approved file E78996
- Case style INT-A-PAK
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level

3500

I _{F(DC)} at T _C	230 A at 100	°C			
ABSOLUTE MAXIMUM RAT	INGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Cathode to anode voltage	V_R		600	V	
Outlier of formal and a section of	I _F	T _C = 25 °C	435	A	
Continuous forward current per leg		T _C = 100 °C	230		
Single pulse forward current	I _{FSM}	Limited by junction temperature	TBD		
Maximum power dissipation per leg	P _D	T _C = 25 °C	781	W	
		T _C = 100 °C	313		
Operating junction and storage temperature range	T _J , T _{Stg}		- 40 to 150	°C	

50 Hz, circuit to base,

all terminals shorted, t = 1 s

 $V_{\text{INS}} \\$

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V_{BR}	I _R = 500 μA	600	-	-	
Forward voltage drop per leg	V _{FM}	I _F = 150 A	-	1.23	1.53	
		I _F = 300 A	-	1.43	1.96	V
		I _F = 150 A, T _J = 125 °C	-	1.11	1.29	
		I _F = 300 A, T _J = 125 °C	-	1.39	1.73	
Maximum reverse leakage current	I _{RM}	T _J = 150 °C, V _R = 600 V	-	-	50	mA

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RMS insulation voltage

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VSKDU300/06PbF

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
Davida and the control of the contro		T _J = 25 °C	I _F = 50 A dl/dt = 200 A/µs V _R = 400 V (per leg)	-	130	165	ns
Reverse recovery time	t _{rr}	T _J = 125 °C		-	195	260	
Peak recovery current	I _{rr}	T _J = 25 °C		-	11	18	А
		T _J = 125 °C		-	20	30	
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	670	1485	nC
		T _J = 125 °C		-	1800	3900	
Peak rate of recovery current	dI _{(rec)M} /dt	T _J = 125 °C		-	-	400	A/µs
Coffnoon factor per log	_	I _F = 50 A, T _J = 25 °C, dl	$/dt = 400 \text{ A/}\mu\text{s}, V_{R} = 200 \text{ V}$	-	0.2	-	
Softness factor per leg s		$I_F = 50 \text{ A}, T_J = 125 ^{\circ}\text{C}, dI/dt = 400 \text{A/}\mu\text{s}, V_R = 200 \text{V}$		-	0.22	-	

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction of storage temperature		T _J , T _{Stg}		- 40 to 150	°C	
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	0.16		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, flat, smooth and greased	0.05		
Mounting	Mounting to heatsink		A mounting compound is recommended and the	4 to G	Nm	
torque ± 10 % busbar			torque should be rechecked after a period of 3 hours to allow the spread of the compound.	4 to 6		
Approximate weight				200	g	
Approximate weight	Approximate weight			7.1	OZ.	
Case style				INT-A-PAK		





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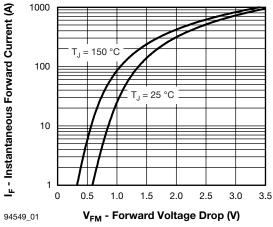


Fig. 1 - Maximum Forward Voltage Drop Characteristics

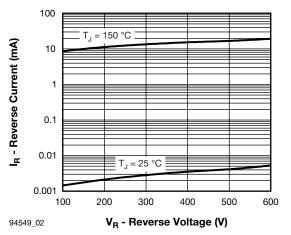


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

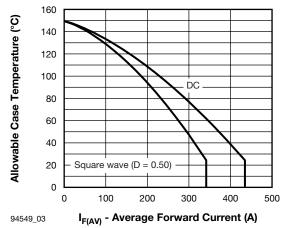


Fig. 3 - Maximum Allowable Case Temperature vs. Average Forward Current

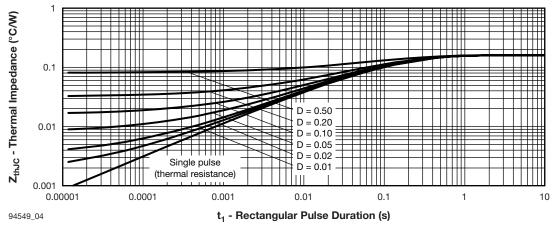


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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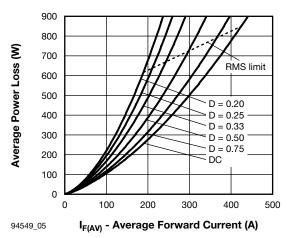


Fig. 5 - Forward Power Loss Characteristics

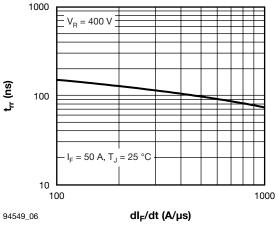


Fig. 6 - Typical Reverse Recovery Time vs. dl_F/dt (Per Leg)

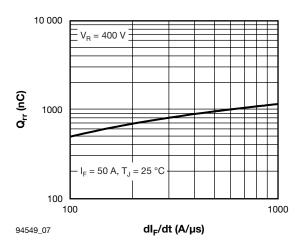


Fig. 7 - Typical Reverse Recovery Charge vs. dl_F/dt (Per Leg)

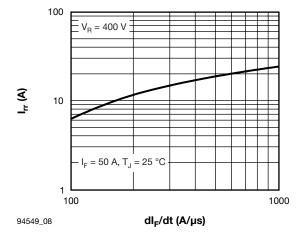


Fig. 8 - Typical Reverse Recovery Current vs. dl_F/dt (Per Leg)



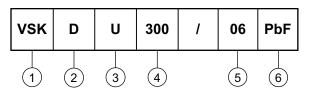


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ORDERING INFORMATION TABLE

Device code



1 - Module type

2 - Circuit configuration:

D = Doubler, 2 diodes in series

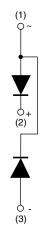
3 - U = Ultrafast diode

Current rating (300 = 300 A)

- Voltage rating (06 = 600 V)

6 - PbF = Lead (Pb)-free

CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95254			

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